

## **High Efficient Surface Mount Rectifiers**

### **FEATURES**

- Glass passivated junction chip.
- Ideal for automated placement
- Fast switching for high efficiency
- High surge current capability
- Moisture sensitivity level: level 1, per J-STD-020
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition
- AEC-Q101 available

### TYPICAL APPLICATION

B





DO-214AC (SMA)

The superior avalanche capability of BYG23M is specially suited for free-wheeling, clamping, snubbering, demagnetization in power supplies and other power switching applications.

### **MECHANICAL DATA**

Case: DO-214AC (SMA) Molding compound, UL flammability classification rating 94V-0 Base P/N with suffix "G" on packing code - green compound (halogen-free) Terminal: Matte tin plated leads, solderable per JESD22-B102 Meet JESD 201 class 2 whisker test Polarity: Indicated by cathode band Weight: 0.064 g (approximately)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERSTICS (T <sub>A</sub> =25°C unless otherwise noted)				
PARAMETER	SYMBOL	BYG23M	UNIT  V V V	
Maximum repetitive peak reverse voltage	V <sub>RRM</sub> V <sub>RMS</sub>	1000 700		
Maximum RMS voltage				
Maximum DC blocking voltage	V <sub>DC</sub>	1000	V	
Maximum average forward rectified current (@T <sub>A</sub> =65°C)	I <sub>F(AV)</sub>	1.5	A	
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	50	A	
Maximum instantaneous forward voltage (Note 1) @ 1 A	V <sub>F</sub>	1.7	V	
Maximum reverse current @ rated VR T <sub>J</sub> =25°C T <sub>J</sub> =100°C T <sub>J</sub> =125°C	I <sub>R</sub>	1 15 50	μΑ	
Pulse energy in avalanche mode, non repetitive (Inductive load switch off ) $T_A$ =25 $^\circ$ C, I <sub>(BR)R</sub> =1.23A	E <sub>RSM</sub>	30	mJ	
Maximum reverse recovery time (Note 2)	t <sub>rr</sub>	65	ns	
Typical junction capacitance (Note 3)	CJ	15	pF	
Typical thermal resistance	R <sub>θJA</sub>	70	°C/W	
Operating junction temperature range	TJ	- 55 to +150	°C	
Storage temperature range	T <sub>STG</sub>	- 55 to +150	°C	

Note 1: Pulse Test with PW=300µs, 1% Duty Cycle

Note 2: Reverse Recovery Test Conditions:  $I_F$ =0.5A,  $I_R$ =1.0A,  $I_{RR}$ =0.25A

Note 3: Measured at 1 MHz and Applied Reverse Voltage of 4.0Volts.



### Taiwan Semiconductor

ORDERING INFORMATION					
PART NO.	PACKING CODE	PACKING CODE SUFFIX	PACKAGE (Note 1)	PACKING	
BYG23M	R3	G	SMA	1,800 / 7" Plastic reel	
	R2		SMA	7,500 / 13" Paper reel	
	M2		SMA	7,500 / 13" Plastic reel	
	F3		Folded SMA	1,800 / 7" Plastic reel	
	F2		Folded SMA	7,500 / 13" Paper reel	
	F4		Folded SMA	7,500 / 13" Plastic reel	
	E3		Clip SMA	1,800 / 7" Plastic reel	
	E2		Clip SMA	7,500 / 13" Plastic reel	

Note 1: Package "SMA" and "Folded SMA" are AEC-Q101 qualified, Clip SMA doesn't.

EXAMPLE					
PREFERRED PART NO.	PART NO.	PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION	
BYG23M R3	BYG23M	R3		AEC-Q101 qualified	
BYG23M R3G	BYG23M	R3	G	AEC-Q101 qualified Green compound	

### **RATINGS AND CHARACTERISTICS CURVES**

DERATING

(T<sub>A</sub>=25°C unless otherwise noted)

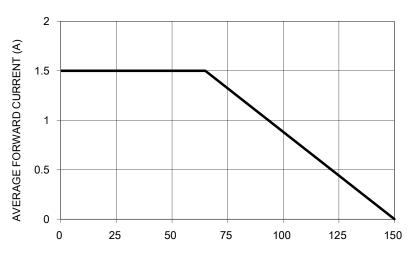


FIG.1 MAXIMUM AVERAGE FORWARD CURRENT



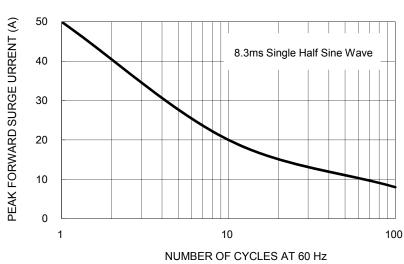
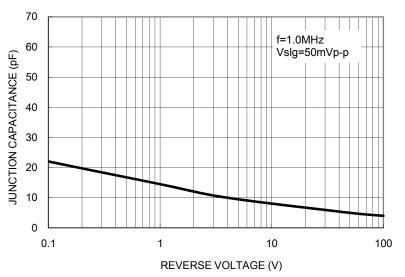


FIG. 3 MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

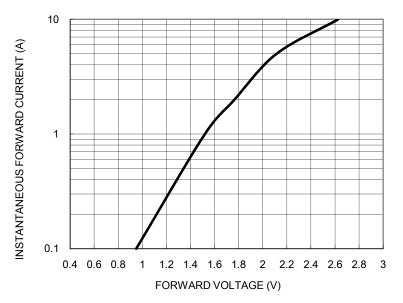
### FIG. 4 TYPICAL JUNCTION CAPACITANCE



## FIG. 2 TYPICAL REVERSE CHARACTERISTICS

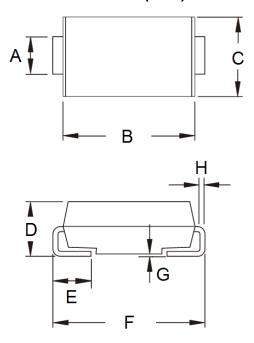


#### FIG. 5 TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

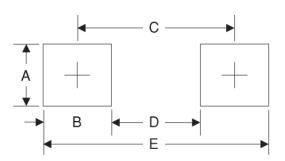


# PACKAGE OUTLINE DIMENSIONS

DO-214AC (SMA)



### SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
A	1.68	0.066
В	1.52	0.060
С	3.93	0.155
D	2.41	0.095
E	5.45	0.215

### **MARKING DIAGRAM**



P/N =Specific Device Code Green Compound

Date Code

Factory Code

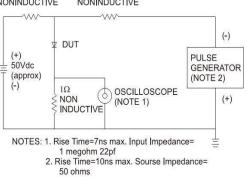
Document Number: DS\_D1411087

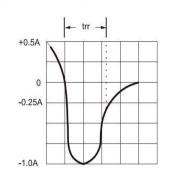
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DIM.	Unit (mm)		Unit (inch)	
	Min	Max	Min	Max
А	1.27	1.58	0.050	0.062
В	4.06	4.60	0.160	0.181
С	2.29	2.83	0.090	0.111
D	1.99	2.50	0.078	0.098
E	0.90	1.41	0.035	0.056
F	4.95	5.33	0.195	0.210
G	0.10	0.20	0.004	0.008
Н	0.15	0.31	0.006	0.012

FIG.6 REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

#### 50Ω NONINDUCTIVE 10Ω NONINDUCTIVE





G =

F =

YW =



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